



ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Cathode to anode breakdown voltage	V_{BR}	I _R = 100 μA			-	-			
Maximum forward voltage	V _{FM}	I _F = 25 A		-	1.3	1.7	V		
		I _F = 50 A	See fig. 1	-	1.5	2.0			
		I _F = 25 A, T _J = 125 °C		-	1.3	1.7			
Maximum reverse	I _{RM}	V _R = V _R rated	See fig. 2	-	1.5	20	- μΑ		
leakage current		$T_J = 125$ °C, $V_R = 0.8 \times V_R$ rated	See lig. 2	-	600	2000			
Junction capacitance	C _T	$V_R = 200 \text{ V}$ See fig. 3		-	55	100	pF		
Series inductance	L _S	Measured lead to lead 5 mm from pa	-	8.0	-	nH			

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time See fig. 5	t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	23	-			
	t _{rr1}	T _J = 25 °C	I _F = 25 A dI _F /dt = 200 A/μs V _R = 200 V	-	50	75	ns		
	t _{rr2}	T _J = 125 °C		-	105	160			
Peak recovery current See fig. 6	I _{RRM1}	T _J = 25 °C		-	4.5	10	A nC		
	I _{RRM2}	T _J = 125 °C		-	8.0	15			
Reverse recovery charge See fig. 7	Q _{rr1}	T _J = 25 °C		-	112	375			
	Q _{rr2}	T _J = 125 °C		-	420	1200	iiC		
Peak rate of fall recovery current during t _b See fig. 8	dI _{(rec)M} /dt1	T _J = 25 °C		-	250	ı	- A/μs		
	dI _{(rec)M} /dt2	T _J = 125 °C		-	160	-			

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C			
Thermal resistance, junction to case	R _{thJC}		-	-	1.0	K/W			
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	N VV			
Weight			-	2.0	-	g			
			-	0.07	=	OZ.			
Marking device		Case style TO-263AB (D ² PAK)	HFA25TB60S						



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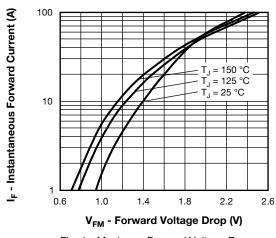


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

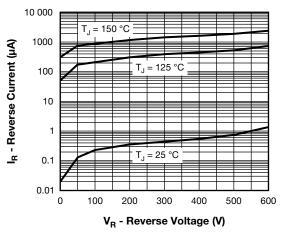


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

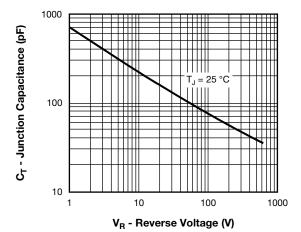


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

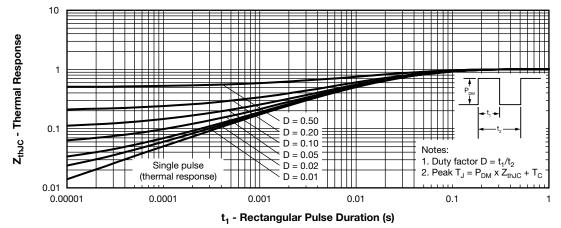


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics





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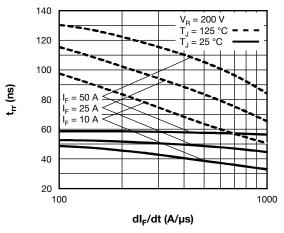


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

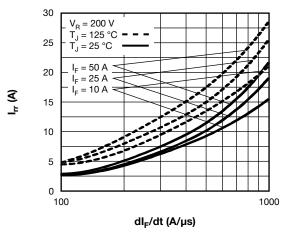


Fig. 6 - Typical Recovery Current vs. dl_F/dt

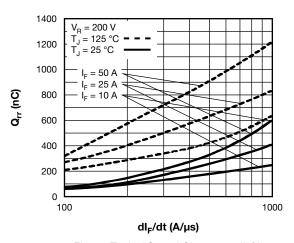


Fig. 7 - Typical Stored Charge vs. dl_F/dt

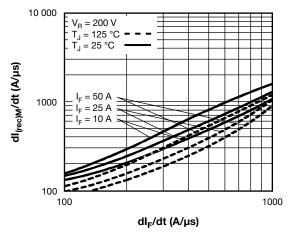


Fig. 8 - Typical dl_{(rec)M}/dt vs. dl_F/dt

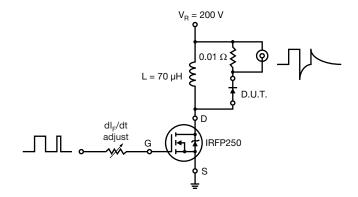
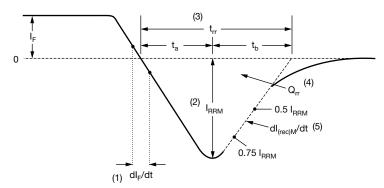


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

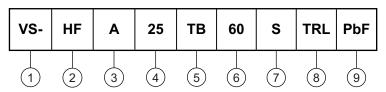
(5) dI_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - HEXFRED® family

3 - Process designator: A = electron irradiated

4 - Current rating (25 = 25 A)

5 - Package outline (TB = TO-220, 2 leads)

- Voltage rating (60 = 600 V)

7 - $S = D^2PAK$

8 - • None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

9 - • PbF = lead (Pb)-free, for tube packaged

• P = lead (Pb)-free, for tape and reel packaged

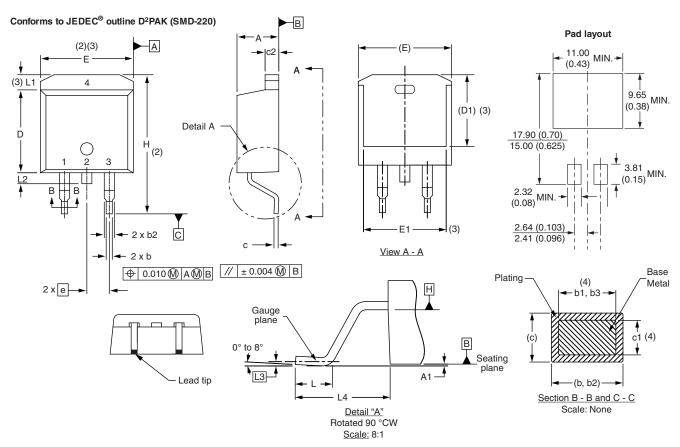
ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-HFA25TB60SPBF	50	1000	Antistatic plastic tube						
VS-HFA25TB60STRRP	800	800	13" diameter reel						
VS-HFA25TB60STRLP	800	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95046						
Part marking information	www.vishay.com/doc?95054						
Packaging information	www.vishay.com/doc?95032						



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL MILLIM	ETERS	S INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES		
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54 BSC		0.100 BSC		
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25 BSC		0.010 BSC		
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB

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